

Electronic Instrumentation

Lecturer: Kofi Makinwa

K.A.A.Makinwa@TUDelft.NL

015-27 86466
Room. HB13.270 EWI building

Teaching Assistant: Saleh Heidary

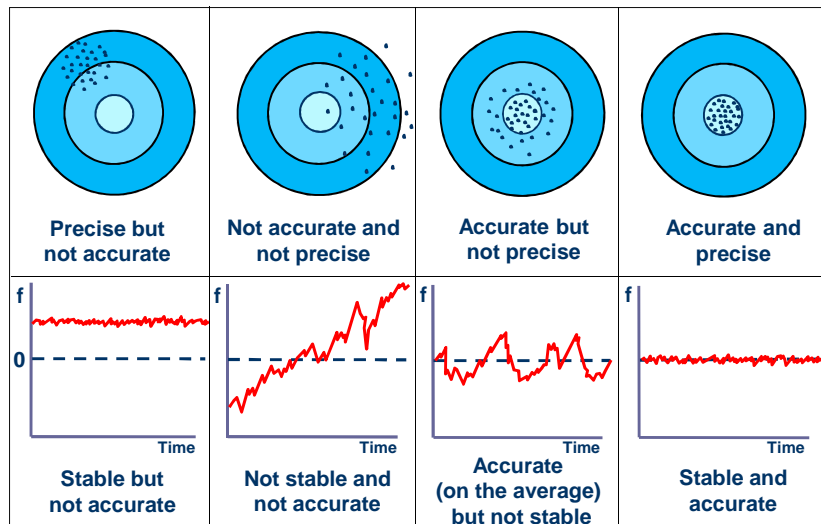
S.H.Shalmany@TUDelft.NL

1

- Goal of a measurement system:
 - Get the most out of a measurement or sensor
 - in terms of information quality

- How?
 - Filtering (averaging) and shielding
 - Compensation (e.g. feed-forward)
 - Correction (e.g. auto-zeroing)
 - Feedback
 - Modulation and correlation

2



4-2

3

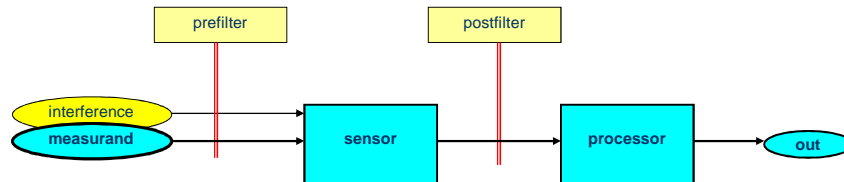
Add-on techniques:

- filtering
 - prefiltering
 - postfiltering
 - correlation
- correction
 - post-processing (e.g. auto-zeroing, linearization)

Built in techniques:

- compensation
 - balancing
 - bridge
- feedback
 - requires an inverse transducer (actuator)
- modulation
 - chopping
 - spinning
 - swapping

4



- reduces additive errors
- in a specified frequency band
- reduces the effects of thermal noise

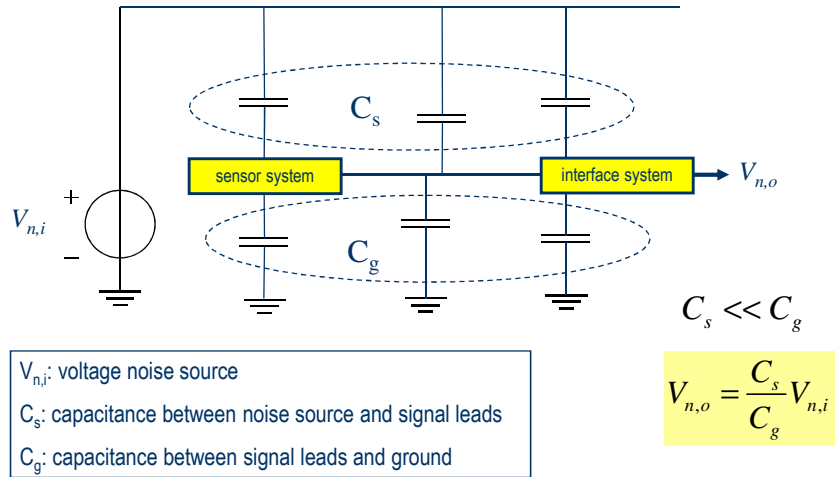
5

- Pre-filtering (prior to transduction)
- Mitigates the effects of:
 - *electrically induced* signals (capacitive) ⇒ **shielding**
 - *magnetically induced* signals (inductive) ⇒ reducing loop area; **shielding**
 - changes in environmental *temperature* ⇒ **isolation**
 - unwanted *optical* input ⇒ **optical filters**
 - *mechanical* disturbances (shocks, vibrations) ⇒ **dampers**
 -

6

Electrically-induced interference

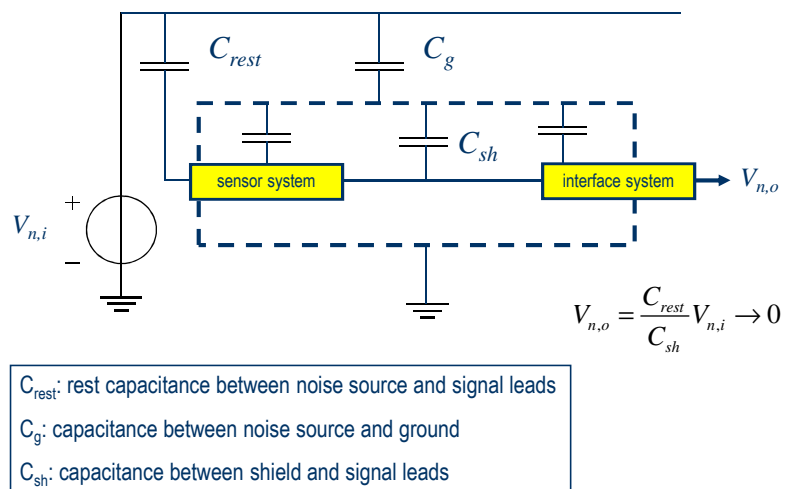
ET8.017
El. Instr.



7

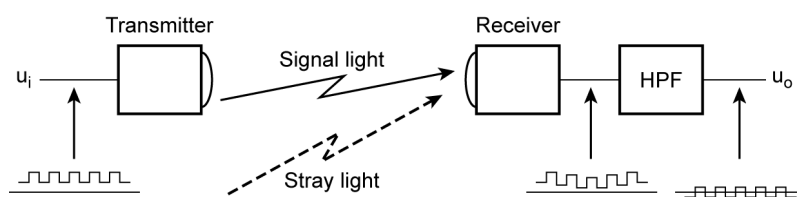
Shielding

ET8.017
El. Instr.



8

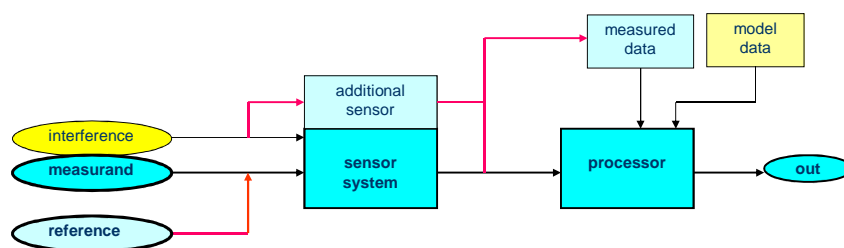
- post-filtering (after transduction)
- in the electrical domain
 - low pass, high pass, band pass
 - first order, higher order
 - characteristic (Butterworth, Bessel,...)
 - analog, digital
 - Matched filtering
- If the time-domain characteristics of the measurand are known, correlation and windowing techniques can be used



- High-pass filter removes 50Hz interference from ambient light sources

- Add-on to an existing system
 - model-based correction (after calibration)
 - correction of cross sensitivities (extra sensors)
- Correcting for additive errors
 - auto-zeroing
 - CDS
- Correcting for multiplicative errors
 - linearization
 - 3-signal method (calibration of linear systems)

11

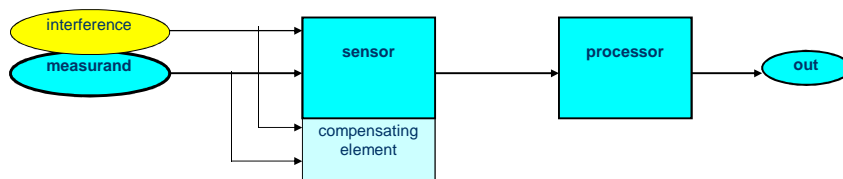


- Can cancel both additive and multiplicative errors
- But additional sensors and multiple errors limit the achievable accuracy

12

- where?
 - pre-compensation (inherent design)
 - post-compensation (model-based signal correction)
- which strategy?
 - balancing
 - feedforward
 - feedback (with an actuator)

13



- reduces (common) additive errors
- improves dynamic range

Examples

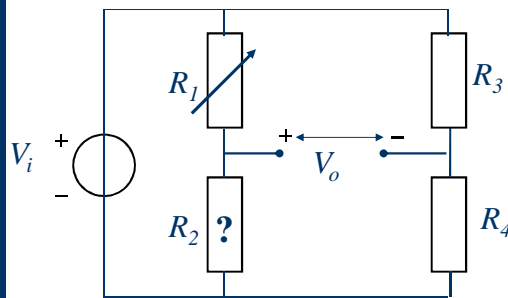
- dummy sensor: used to compensate for environmental influences
- Extra temperature sensor: used to compensate for unwanted temperature dependencies

14

Bridge compensator

ET8.017
El. Instr.

- for accurate *absolute* measurements of resistances



$$V_o = \left(\frac{R_2}{R_1 + R_2} - \frac{R_4}{R_3 + R_4} \right) V_i$$

$$R_2 R_3 = R_1 R_4$$

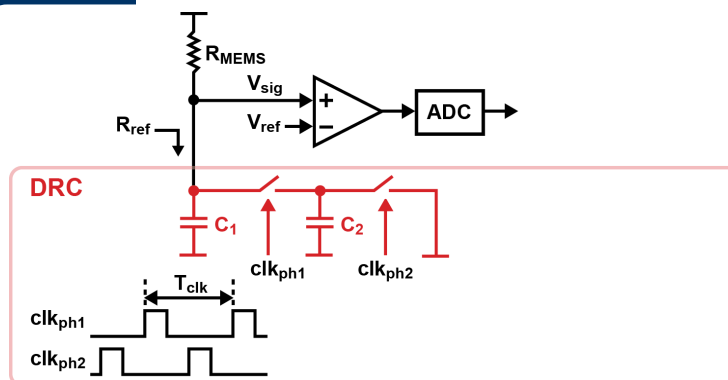
$$R_2 = R_1 \left(\frac{R_4}{R_3} \right)$$

- Insensitive to CM disturbances e.g. temperature
- but requires an *accurate*, adjustable resistor

15

Switched Cap "Resistor"

ET8.017
El. Instr.



- Switched cap network emulates an adjustable resistance
 - Effective resistance value: $R_{ref} = T_{clk}/C_2$

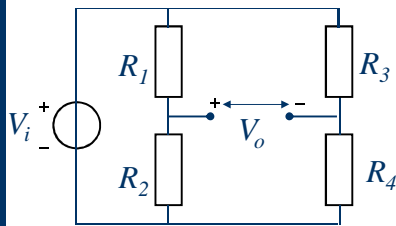
M. Perrot et al., ISSCC 2012

16

Bridge indicator

ET8.017
El. Instr.

- measures small changes with respect to "an initial" value



$$V_o = \left(\frac{R_2}{R_1 + R_2} - \frac{R_4}{R_3 + R_4} \right) V_i$$

initially: resistances have values such that

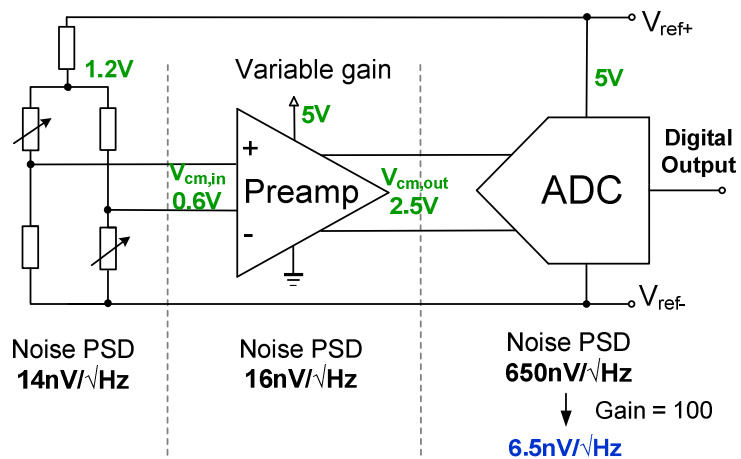
$$R_{02}R_{03} = R_{01}R_{04}$$

- but output is sensitive to drift and error in V_i

17

Ratiometric readout

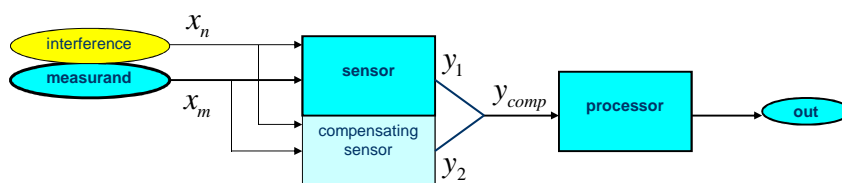
ET8.017
El. Instr.



ADC and bridge use the same reference voltage V_{ref}
 \Rightarrow errors in V_{ref} do not affect digital output

18

- Consider the ratiometric system shown on the previous slide. If the noise densities shown for the bridge, preamp and ADC, correspond to the situation when the bridge is balanced:
 1. Calculate the resistance of each arm of the bridge
 2. If the measurement BW is 10Hz, how many bits of resolution must the ADC have in order to ensure that the resolution of the system is determined by thermal noise rather than by quantization errors.
 3. If the ADC has 20-bit resolution (**not** necessarily the answer to question 2 above) what percentage change in the resistance of a bridge element corresponds to a 1LSB change in its digital output.



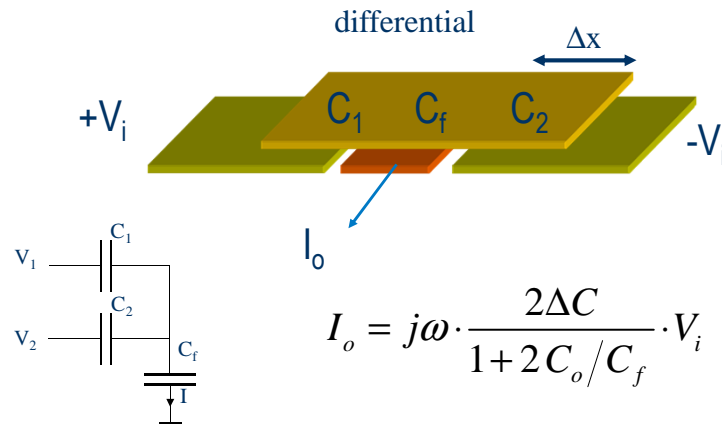
$$\left. \begin{aligned} y_1 &= S_{m1}x_m + S_{n1}x_n \\ y_2 &= -S_{m2}x_m + S_{n2}x_n \end{aligned} \right\} \begin{array}{l} \text{opposite sensitivity} \\ \text{by design!} \end{array}$$

S_{m1} : sensitivity sensor 1 to measurand
 S_{m2} : sensitivity sensor 2 to measurand
 S_{n1} : sensitivity sensor 1 to interference
 S_{n2} : sensitivity sensor 2 to interference

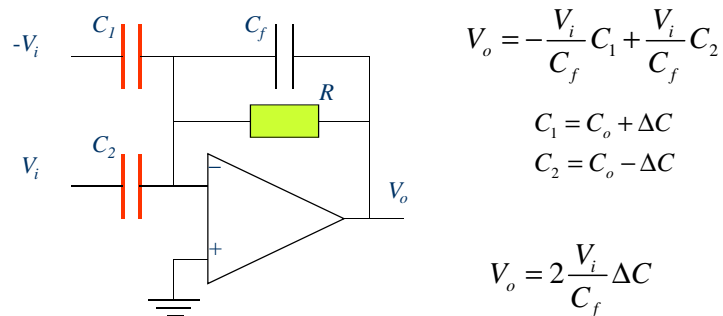
$$y_{comp} = (S_{m1} + S_{m2})x_m + (S_{n1} - S_{n2})x_n$$

$$y_{comp} = 2S_m x_m + \Delta S_n x_n = 2S_m \left(x_m + \frac{\Delta S_n}{2S_m} x_n \right)$$

$$CMRR = \frac{2S_m}{\Delta S_n}$$



21



- The resistance R reduces drift
- But it introduces extra noise and gives rise to a frequency-dependent transfer function

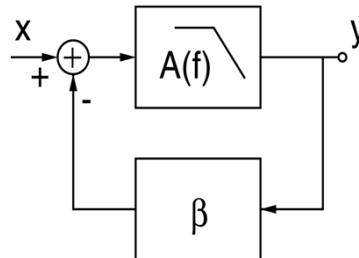
22

If $A(f) \cdot \beta \gg 1 \Rightarrow A_{CL} \cong 1/\beta$.

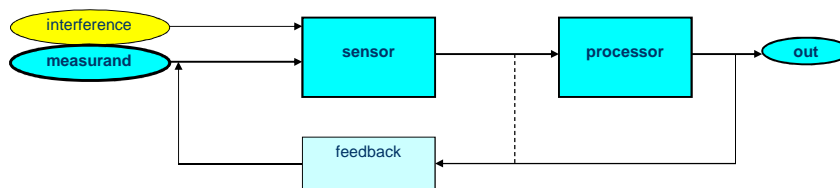
For moderate $1/\beta$, op-amp
DC gain is large enough!

$\beta \Rightarrow$ Resistor/Capacitor ratios.
Resistors \Rightarrow 0.01%, 5 ppm/°C
Capacitors \Rightarrow 1%, 500 ppm/°C

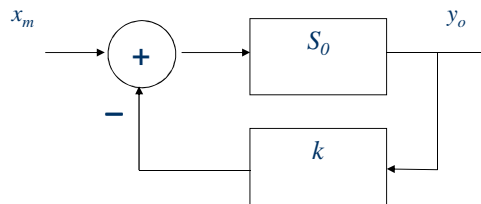
$\Rightarrow A_{CL}$ can be very accurately defined.



$$A_{CL} = \frac{x}{y} = \frac{A}{(1+A\beta)}$$



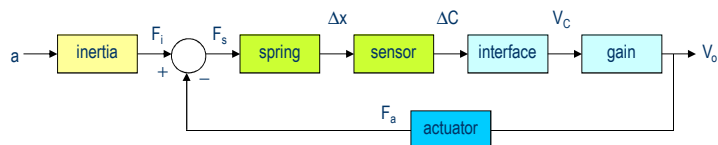
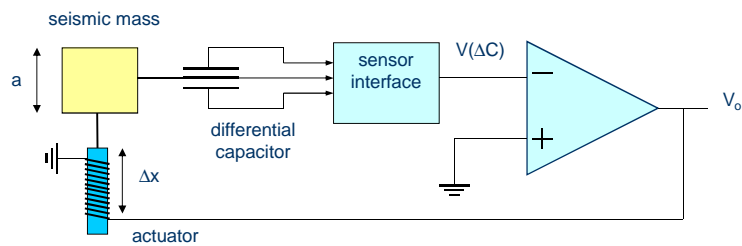
- reduces multiplicative errors
- improves dynamic behaviour



$$S_f = \frac{S_0}{1 + S_0 \cdot k}$$

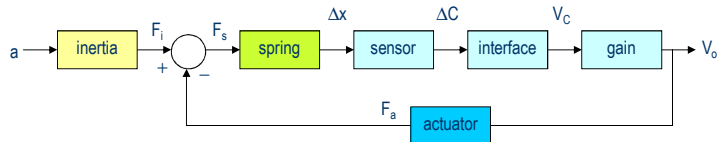
$$\frac{dS_f}{S_f} = \frac{1}{1 + k \cdot S_0} \cdot \frac{dS_0}{S_0}$$

- Prerequisites for effective error reduction are:
 - high forward path transfer
 - stable feedback path transfer



Analysis of a feedback accelerometer (1)

ET8.017
El. Instr.



H_i : transfer from acceleration a to inertial force F_i
 H_s : transfer from force F_s on sensor to displacement Δx
 H_e : transfer from displacement to output voltage V_o
 H_a : transfer of actuator: from output voltage V_o to F_a

$$V_o = \frac{H_s H_e}{1 + H_a H_s H_e} H_i a$$

if : $H_a H_s \gg 1$:

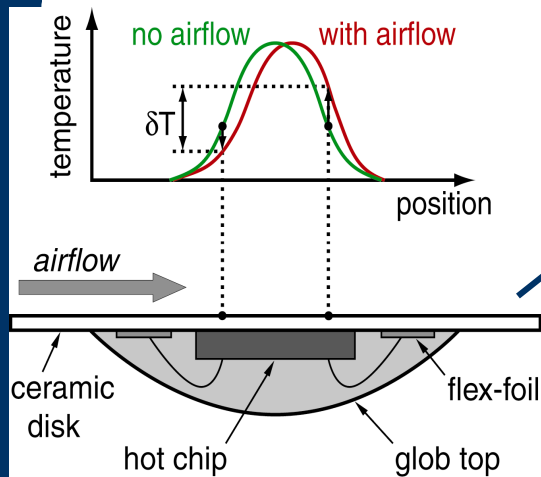
$$V_o = \frac{H_i}{H_a} a$$

Independent of system parameters of the spring, sensor, interface, gain factor
Transfer function depends only on **mass** and **actuator**

27

Example 2: Wind sensor

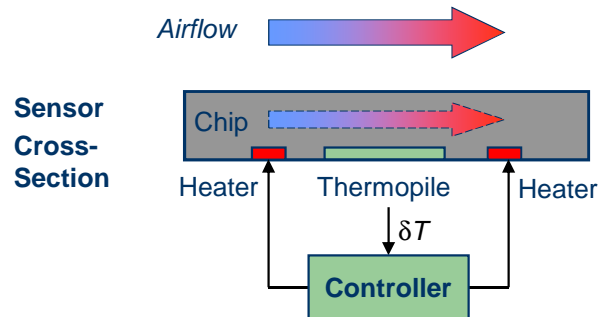
ET8.017
El. Instr.



28

Thermal balancing

ET8.017
El. Instr.



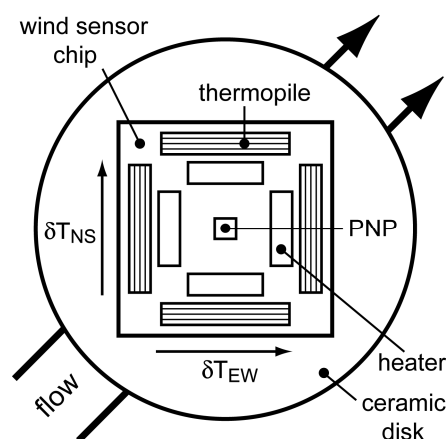
- Airflow induces an on-chip temperature gradient δT
- This is sensed by an on-chip thermopile and cancelled by a pair of heaters
- Transfer function only depends on the heaters (resistors) and their supply voltage

29

Wind sensor chip

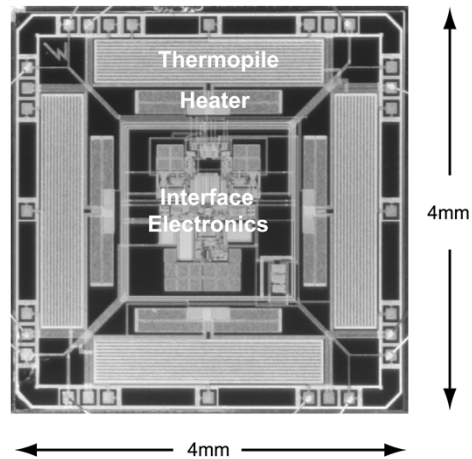
ET8.017
El. Instr.

- On-chip heaters
- Thermopiles \Rightarrow wind induced temperature differences δT_{NS} & δT_{EW}
- On-chip controllers nulls δT_{NS} & δT_{EW}
- $|\delta P| \Rightarrow$ wind speed
- $\arg(\delta P) \Rightarrow$ wind direction

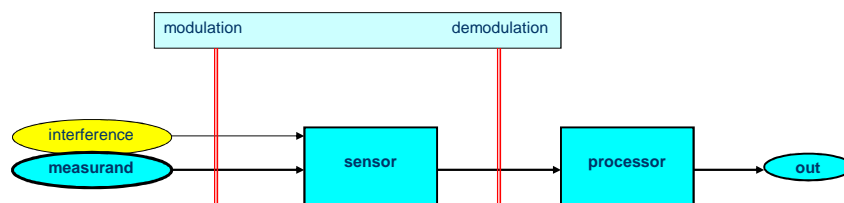


30

- Digital outputs δP_{NS} & δP_{EW}
- After calibration:
Speed error: $\pm 4\%$
Angle error: $\pm 2^\circ$
- Comparable to conventional wind sensors
- But no moving parts!



31

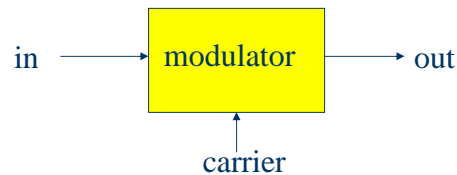


- Basic ideas: shift information to a quiet frequency bands OR make information more robust
- Reduces additive errors
- In particular, offset, drift, LF noise and gain error

32

Modulation types

ET8.017
El. Instr.

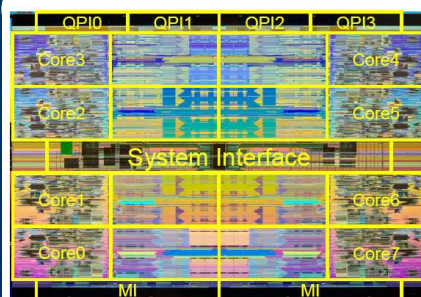


- AM modulation: Chopping, synchronous detection, dynamic element matching
- FM modulation: Used to make information more robust to amplitude variations
- Pulse-width (or duty-cycle) modulation: also used to make information more robust to amplitude variations, also used for simple digital-to-analog conversion

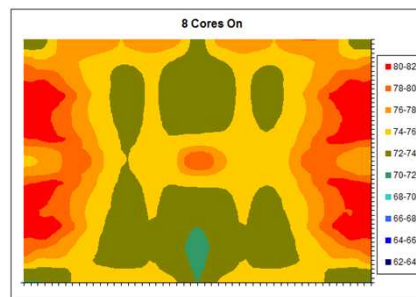
33

The Thermal Management Challenge!

ET8.017
El. Instr.



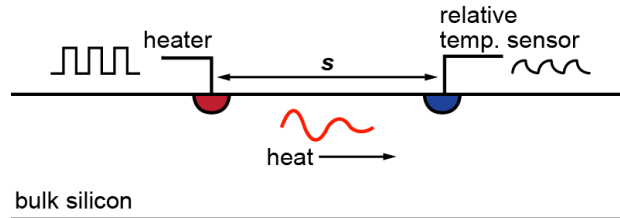
Intel 45nm Xeon



Courtesy of S. Rusu Intel

- SoCs and multi-core processors \Rightarrow multiple hot spots
- Hot spot location depends on (dynamic) workload \Rightarrow multiple (20+) temperature sensors

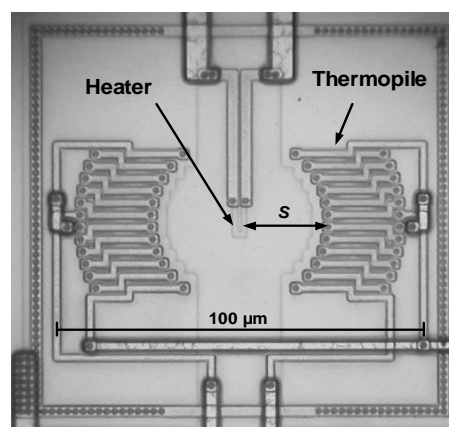
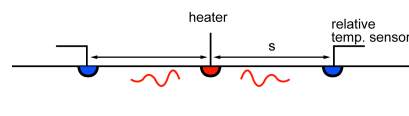
34



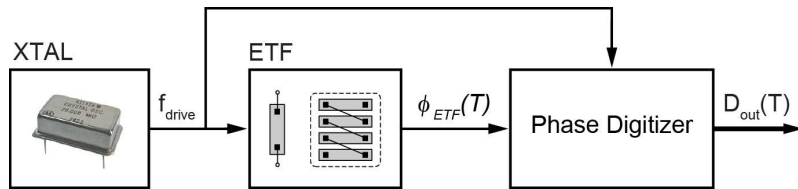
- Heater generates small heat pulses (mWs)
- Temperature sensor picks up delayed pulses (mVs)
- Resulting thermal delay is temperature-dependent
- Exploits the strengths of CMOS technology:
 - Lithography → accurate spacing s
 - Pure silicon substrate → D_{Si} is well-defined
 - Fast circuits measurements → accurate delay

35

- Heater = n⁺-diffusion resistor
- Temp. sensor = p⁺/Al thermopile
- Can be made in any IC process!
- Circular, differential layout for maximum output



36

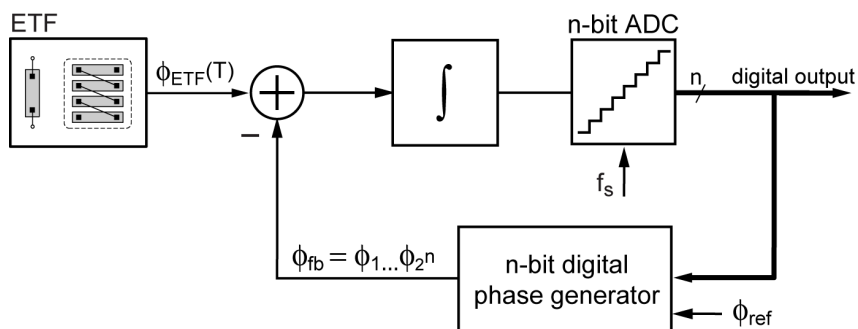


$$\phi_{ETF} \propto s \sqrt{f_{drive} / D_{Si}}$$

- At room temp, $s = 20\mu\text{m}$, $f = 100\text{kHz} \Rightarrow \phi_{ETF} \sim 90^\circ$
- Quartz-crystal clock generates f_{drive} (typ. 100s of kHz)
- ϕ_{ETF} is digitized by a *phase-domain* $\Sigma\Delta$ modulator
- Resolution is mainly limited by ETF's thermal noise

[van Vroonhoven, Makinwa, ISSCC 2008]

37

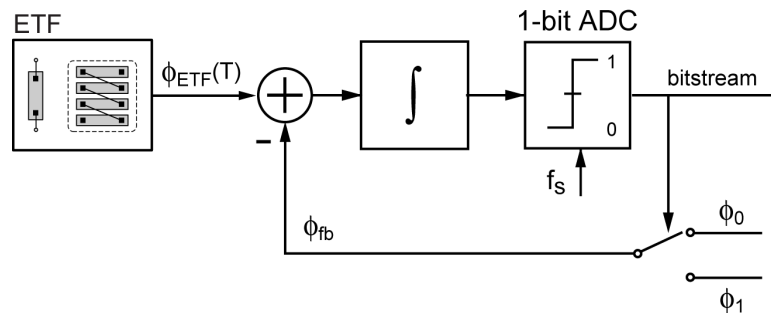


- How to accurately measure the phase of a small (1mVpp) and noisy signal?
- Use feedback, an ADC and a *digital* phase generator
- Then digitally filter the result (few Hz BW)

38

Phase-Domain $\Delta\Sigma$

ET8.017
El. Instr.

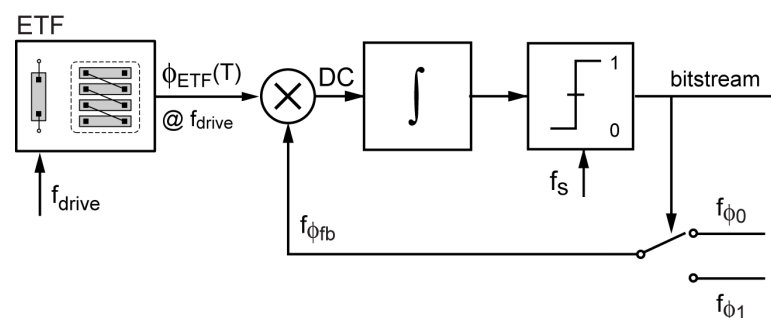


- Since the sensor's BW is so low, we can over-sample its output and then average \Rightarrow a 1-bit ADC is enough!
- This technique is known as sigma-delta modulation
- 12-bit resolution in 0.5Hz BW $\rightarrow f_s > 2\text{kHz} \rightarrow$ easy!

39

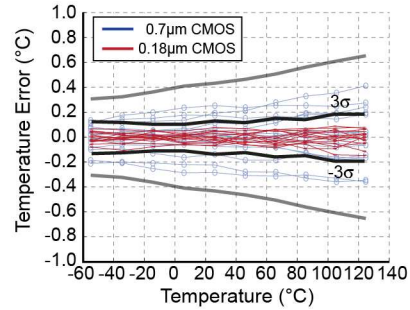
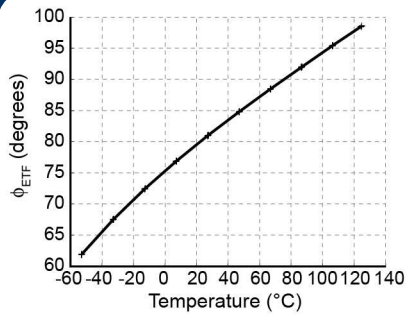
Subtracting phase?

ET8.017
El. Instr.

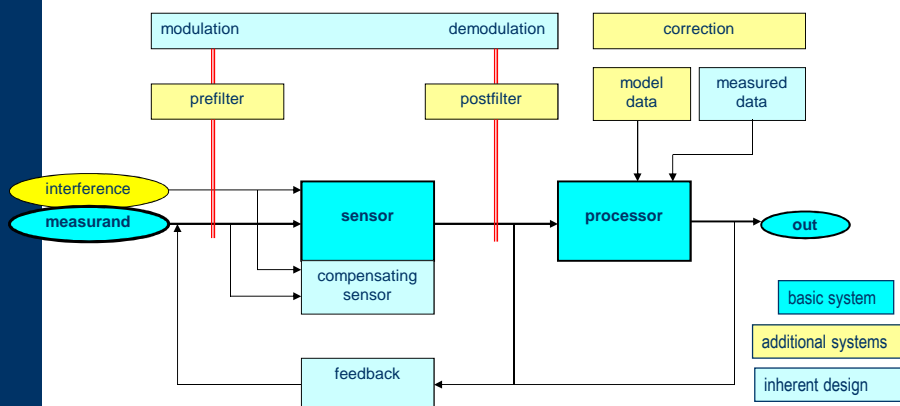


- Use a synchronous detector!
- DAC references are just phase-shifted copies of f_{drive}
 \rightarrow multiplier inputs are at same frequency
- $DC \propto \cos(\phi_{ETF} - \phi_{fb}) = 0$ when $\phi_{fb} = \phi_{ETF} - 90^\circ$
- Approx. linear close to $(\phi_{ETF} - \phi_{fb}) = 90^\circ$

40



- **Untrimmed** spread is mainly limited by lithography
 - $\pm 0.6^{\circ}\text{C}$ (3σ) in $0.7\mu\text{m}$ CMOS
 - $\pm 0.2^{\circ}\text{C}$ (3σ) in $0.18\mu\text{m}$ CMOS (same ETF layout)
- Accurate, and scales!



- The thermal diffusivity of silicon is proportional to $1/T^{1.8}$ where T is absolute temperature
- If an electrothermal filter has a phase shift of 90° at 300K, calculate its phase-shift at the extremes of the military temperature range, i.e. -55°C and 125°C
- A smart TD sensor employs a phase digitizer. How many bits of resolution should it have in order to achieve a temperature-sensing resolution of 0.1°C ?
- If the phase digitizer employs the feedback architecture shown on slide 38 and uses a chopper as a phase detector, what range of phases must its phase DAC provide in order for the sensor to cover the military range?